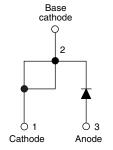


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Fast Soft Recovery Rectifier Diode, 20 A





60 ns

150 °C

Single die

0.6

TO-220AC FULL-PAK

 t_{rr}

 T_J max.

Diode variation

Snap factor

PRODUCT SUMMARY	
Package	TO-220FP
I _{F(AV)}	20 A
V_R	200 V, 400 V, 600 V
V _F at I _F	1.3 V
I _{ESM}	300 A

FEATURES

- 150 °C max. operation junction temperature
- Designed and qualified according to JEDEC-JESD47
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved
- Material categorization:
 For definitions of compliance please see <u>www.vishay.com/doc?99912</u>





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-20ETF0..FP... fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Sinusoidal waveform	20	A			
V_{RRM}		200 to 600	V			
I _{FSM}		300	А			
V _F	10 A, T _J = 25 °C	1.2	V			
t _{rr}	1 A, 100 A/μs	60	ns			
T _J		- 40 to 150	°C			

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-20ETF02FPPbF, VS-20ETF02FP-M3	200	300				
VS-20ETF04FPPbF, VS-20ETF04FP-M3	400	500	5			
VS-20ETF06FPPbF, VS-20ETF06FP-M3	600	700				

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	T _C = 51 °C, 180° conduction half sine wave	20		
Maximum peak one cycle non-repetitive	l	10 ms sine pulse, rated V _{RRM} applied	250	Α	
surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	300		
Maximum I ² t for fusing	12+	10 ms sine pulse, rated V _{RRM} applied	316	A ² s	
	I-t	10 ms sine pulse, no voltage reapplied	442	A-5	
Maximum I ² √t for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	BOL TEST CONDITIONS VALUE			UNITS
Maximum forward voltage drop V _{FM}	V	20 A, T _J = 25 °C		1.30	V
	VFM	60 A, T _J = 25 °C		1.67	V
Forward slope resistance	r _t	T _J = 150 °C		12.5	mΩ
Threshold voltage	V _{F(TO)}	T _J = 150 °C		0.9	V
Maximum reverse leakage current I _{RM}		T _J = 25 °C	V Datad V	0.1	A
	IRM	$V_R = Rated V_{RRM}$	5.0	- mA	

RECOVERY CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •
Reverse recovery time	t _{rr}	I _F at 20 Apk	160	ns	I _{FM} †
Reverse recovery current	I _{rr}	100 A/μs	10	Α	$t_a \mid t_b$
Reverse recovery charge	Q _{rr}	25 °C	1.25	μC	dir/ dt Q _{rr}
Snap factor	S	Typical	0.6		dt I _{RM(REC)}

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistar junction to case	nce,	R_{thJC}	DC operation	2.5	
Maximum thermal resistar junction to ambient	nce,	R_{thJA}		62	°C/W
Typical thermal resistance case to heatsink	·,	R _{thCS}	Mounting surface, smooth and greased	0.5	
Annyayimata waight				2	g
Approximate weight				0.07	OZ.
May ating tayous	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf \cdot in)
				20ETF	02FP
Marking device			Case style TO-220 FULL-PAK	20ETF04FP	
				20ETF	06FP



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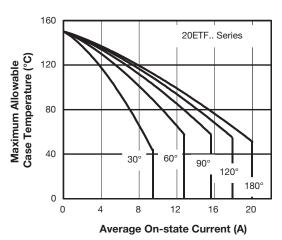


Fig. 1 - Current Rating Characteristics

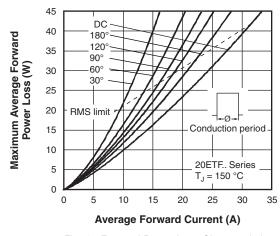


Fig. 4 - Forward Power Loss Characteristics

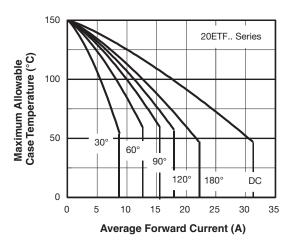


Fig. 2 - Current Rating Characteristics

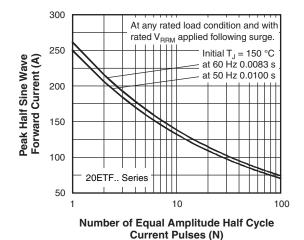


Fig. 5 - Maximum Non-Repetitive Surge Current

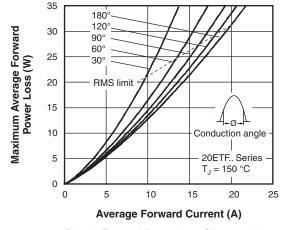


Fig. 3 - Forward Power Loss Characteristics

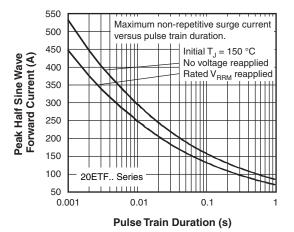


Fig. 6 - Maximum Non-Repetitive Surge Current



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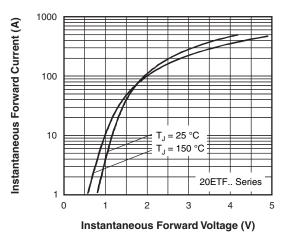


Fig. 7 - Forward Voltage Drop Characteristics

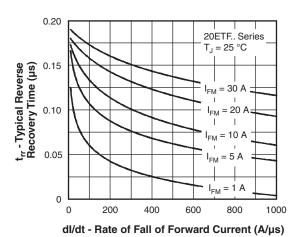


Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

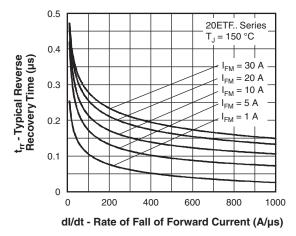


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

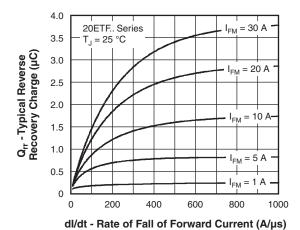


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

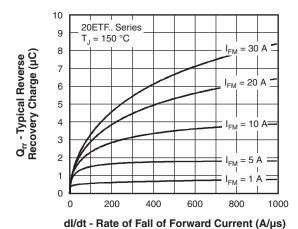


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

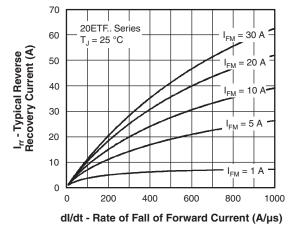


Fig. 12 - Recovery Current Characteristics, T_J = 25 °C

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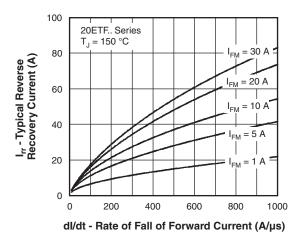


Fig. 13 - Recovery Current Characteristics, T_J = 150 °C

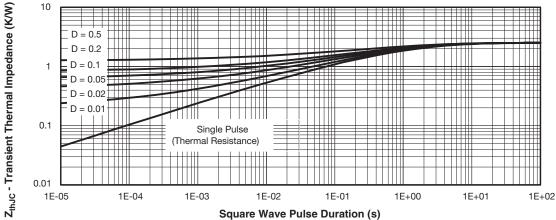
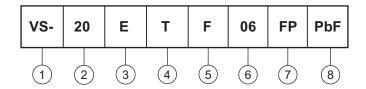


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

3 - Circuit configuration:

E = Single diode

4 - Package:

T = TO-220

5 - Type of silicon:

F = Fast soft recovery rectifier

02 = 200 V 04 = 400 V

- Voltage code x 100 = V_{RRM}

06 = 600 V

7 - FULL-PAK

8 - Environmental digit:

• PbF = Lead (Pb)-free and RoHS compliant

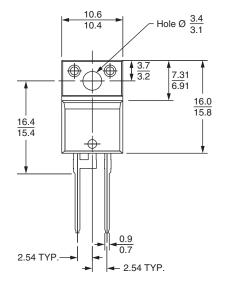
• -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

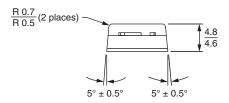
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-20ETF02FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF02FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF04FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF04FP-M3	50	1000	Antistatic plastic tubes		
VS-20ETF06FPPbF	50	1000	Antistatic plastic tubes		
VS-20ETF06FP-M3	50	1000	Antistatic plastic tubes		

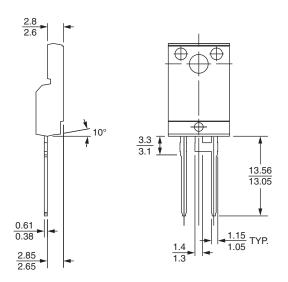
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Part marking information	TO-220 FP PbF	www.vishay.com/doc?95009		
	TO-220 FP -M3	www.vishay.com/doc?95440		
SPICE model		www.vishay.com/doc?95410		

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DIMENSIONS in millimeters







Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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